

HiPerFRED

DPF240X400NA

V_{RRM}	=	400 V
I _{fav}	<i>=</i> 2x	120 A
t _{rr}	=	30 ns

High Performance Fast Recovery Diode Low Loss and Soft Recovery Parallel legs

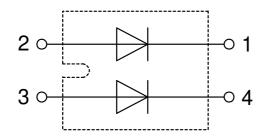
Part number

DPF240X400NA



Backside: isolated





Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
 Soft reverse recovery for low EMI/RFI
- Soft reverse recover;
 Low Irm reduces:
- Power dissipation within the diode
- Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)
- Package: SOT-227B (minibloc)
- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Base plate: Copper
- internally DCB isolatedAdvanced power cycling

Disclaimer Notice

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DPF240X400NA

Fast Diode				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse block	ing voltage	$T_{VJ} = 25^{\circ}C$			400	V
V _{RRM}	max. repetitive reverse blocking v	oltage	$T_{VJ} = 25^{\circ}C$			400	V
I _R	reverse current, drain current	$V_{R} = 400 V$	$T_{VJ} = 25^{\circ}C$			10	μA
		$V_{R} = 400 V$	$T_{vJ} = 150^{\circ}C$			0.5	mA
V _F	forward voltage drop	I _F = 120 A	$T_{vJ} = 25^{\circ}C$			1.25	V
		I _F = 240 A				1.54	V
		I _F = 120 A	T _{vJ} = 150°C			1.06	V
		I _F = 240 A				1.42	V
	average forward current	$T_c = 70^{\circ}C$	T _{vJ} = 150°C			120	Α
		rectangular d = 0.5					
V _{F0}	threshold voltage		T _{vJ} = 150°C			0.71	V
r _F	slope resistance } for power lo	oss calculation only				2.9	mΩ
R _{thJC}	thermal resistance junction to cas	е				0.5	K/W
R _{thCH}	thermal resistance case to heatsin	nk			0.1		K/W
P _{tot}	total power dissipation		$T_c = 25^{\circ}C$			250	W
	max. forward surge current	t = 10 ms; (50 Hz), sine; $V_{R} = 0 V$	$T_{VJ} = 45^{\circ}C$			1.20	kA
C	junction capacitance	$V_{R} = 200 V f = 1 MHz$	$T_{VJ} = 25^{\circ}C$		187		pF
I _{RM}	max. reverse recovery current		$T_{VJ} = 25 °C$		7		Α
		$I_{\rm F} = 120 \text{A}; V_{\rm B} = 240 \text{V}$	T _{vJ} = 125 °C		18		Α
t _{rr}	reverse recovery time	$\begin{cases} I_{F} = 120 \text{ A}; V_{R} = 240 \text{ V} \\ -di_{F} / dt = 200 \text{ A} / \mu \text{s} \end{cases}$	$T_{VJ} = 25 \degree C$		30		ns
	-)	T _{vJ} = 125 °C		140		ns

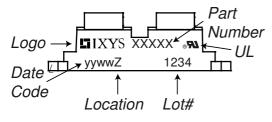
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DPF240X400NA

Package SOT-227B (minibloc)				Ratings				
Symbol	Definition	Conditions			min.	typ.	max.	Unit
I _{RMS}	RMS current	per terminal					150	Α
\mathbf{T}_{v_J}	virtual junction temperature				-40		150	°C
T _{op}	operation temperature				-40		125	°C
T _{stg}	storage temperature				-40		150	°C
Weight						30		g
M _D	mounting torque				1.1		1.5	Nm
M _T	terminal torque				1.1		1.5	Nm
d _{Spp/App}	creepage distance on surface	atriking diatanaa through air	terminal to terminal	10.5	3.2			mm
d _{Spb/Apb}	creepage distance on surface	Striking distance through an	terminal to backside	8.6	6.8			mm
V	isolation voltage	t = 1 second			3000			۷
		t = 1 minute	50/60 Hz, RMS; liso∟ ≤ 1 mA		2500			v

Product Marking



Part description

- D = Diode P = HiPerFRED
- F = ultra fast240 = Current Rating [A]
- X = Parallel legs 400 = Reverse Voltage [V]
- NA = SOT-227B (minibloc)

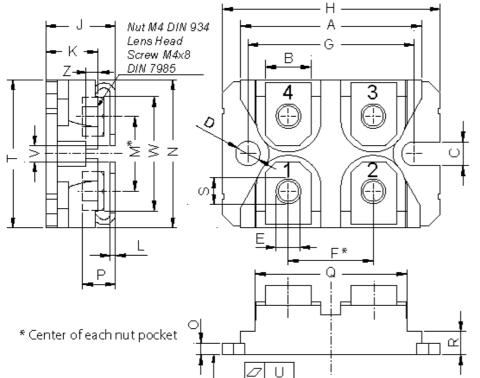
	Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
ſ	Standard	DPF240X400NA	DPF240X400NA	Tube	10	499554

Equivalent Circuits for Simulation		* on die level	$T_{VJ} = 150^{\circ}C$	
	- Ro-	Fast Diode		
V _{0 max}	threshold voltage	0.71		V
$\mathbf{R}_{0 \max}$	slope resistance *	1.01		mΩ

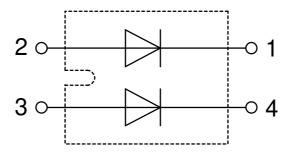
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Outlines SOT-227B (minibloc)



Dim.	Millimeter		Inches		
Dim.	min	max	min	max	
Α	31.50	31.88	1.240	1.255	
B	7.80	8.20	0.307	0.323	
С	4.09	4.29	0.161	0.169	
D	4.09	4.29	0.161	0.169	
E	4.09	4.29	0.161	0.169	
F	14.91	15.11	0.587	0.595	
G	30.12	30.30	1.186	1.193	
Н	37.80	38.23	1.488	1.505	
J	11.68	12.22	0.460	0.481	
К	8.92	9.60	0.351	0.378	
L	0.74	0.84	0.029	0.033	
M	12.50	13.10	0.492	0.516	
Ν	25.15	25.42	0.990	1.001	
0	1.95	2.13	0.077	0.084	
Ρ	4.95	6.20	0.195	0.244	
Q	26.54	26.90	1.045	1.059	
R	3.94	4.42	0.155	0.167	
S	4.55	4.85	0.179	0.191	
Т	24.59	25.25	0.968	0.994	
U	-0.05	0.10	-0.002	0.004	
V	3.20	5.50	0.126	0.217	
W	19.81	21.08	0.780	0.830	
Ζ	2.50	2.70	0.098	0.106	



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